

Boron Carbide (B4C) Sputtering Targets

Material Type	Boron Carbide	Theoretical Density (g/cc)	2.37
Symbol	B4C	Z Ratio	**1.00
Melting Point (°C)	2,350	Sputter	RF
Purity:	99.9%, 99.95%, 99.99%	Max Power Density	30
		(Watts/Square Inch)	
		Type of Bond	Indium